

ROITHNER LASERTECHNIK GIRDH

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LED36-TEC

TECHNICAL DATA



Mid-Infrared Light Emitting Diode

Light Emitting Diodes with central wavelength 3.65 μ m series are based on heterostructures grown on InAs substrates by MOCVD. InAsSb is used in the active layer. Wide band gap solid solutions InAsSbP with P content 50% are used for good electron confinement.

LED36-SMD3 has a stable ouput power and a lifetime more then 80000 hours.

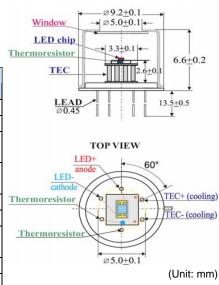
Features

- Structure: InAsSb/InAsSbP
 Peak Wavelength: typ. 3.65 µm
- Optical Ouput Power: typ. 30 μW qCW
- Package: TO-5, with TEC, thermistor and window

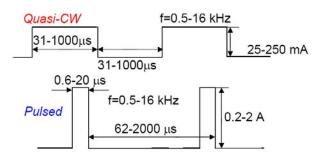


Specifications

Item	Condition	Rating			Unit
		Min.	Тур.	Max.	Oilit
Peak Wavelength	T=300 K	3.60	3.65	3.70	μm
FWHM	150 mA CW	0.40	0.50	0.60	μm
Quasi-CW Optical Power	200 mA qCW	20	30	40	μW
Pulsed Optical Power	1 A	180	200	220	mW
Switching Time	T=300 K	10	20	30	ns
Operation Voltage	200 mA qCW	0.2	-	1.0	V
Operating Temperature	-240 +50				°C
Emitting Area	300x300				μm
Soldering Temperature	180				°C
Package	TO-5, with built-in thermocooler, thermoresistor, with cap and window				



Operating Regime



Quasi-CW

- Maximum current 220 mA
- Recommended current 150-200mA

Pulsed

 Maximum current 1 A (puls lenght 500 ns, repetition rate 2kHz)

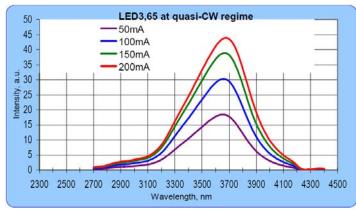


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Typical Performance Curves



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